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- Function, Pinout, and Drive Compatible
   With FCT and F Logic
- Reduced V<sub>OH</sub> (Typically = 3.3 V) Versions of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)
- Fully Compatible With TTL Input and Output Logic Levels
- 64-mA Output Sink Current
   32-mA Output Source Current

#### **SO PACKAGE** (TOP VIEW) S 16 VCC $Q_A$ 15 QD 14 I I<sub>OD</sub> I<sub>OA</sub> I<sub>1A</sub> L 13 I<sub>1D</sub> 12 I I<sub>1C</sub> $I_{1B}$ 11 🛮 I<sub>0C</sub> $I_{0B}$ 10 🛮 Q<sub>C</sub> $Q_B$ GND 9 ∏ CP

#### description

The CY74FCT399T is a high-speed quad 2-input register that selects four bits of data from either of two sources (ports) under control of a common select (S) input. Selected data are transferred to a 4-bit output register synchronous with the low-to-high transition of the clock (CP) input. The 4-bit D-type output register is fully edge triggered. The data inputs  $(I_{0X}, I_{1X})$  and S input must be stable only one setup time prior to, and hold time after, the low-to-high transition of CP for predictable operation. The CY74FCT399T has noninverted outputs.

This device is fully specified for partial-power-down applications using l<sub>off</sub>. The l<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### PIN DESCRIPTION

NAME	DESCRIPTION
S	Common select input
CP	Clock-pulse input (active rising edge)
I <sub>0</sub>	Data inputs from source 0
I <sub>1</sub>	Data inputs from source 1
Q	Register noninverted outputs

#### ORDERING INFORMATION

TA	PACKAGET		PACKAGET		SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
160	SOIC - SO	Tube	6.1	CY74FCT399CTSOC	FCT399C		
–40°C to 85°C	3010 = 30	Tape and reel	6.1	CY74FCT399CTSOCT	FC1399C		
	0010 00	Tube	7	CY74FCT399ATSOC	FCT399A		
	SOIC - SO	Tape and reel	7	CY74FCT399ATSOCT	FC1399A		

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

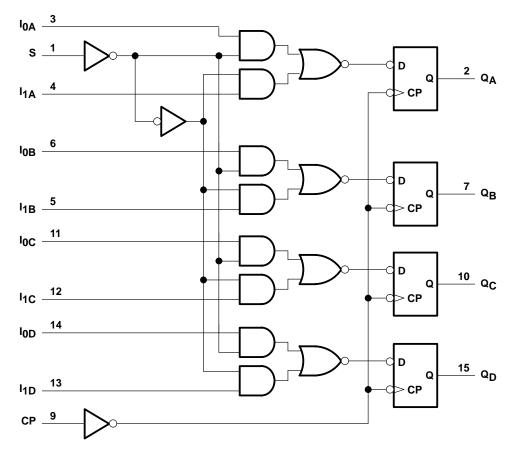


#### **FUNCTION TABLE**

	INPUTS	OUTPUT	
S	I <sub>0</sub>	l <sub>1</sub>	Q
ı	I	Х	L
- 1	h	Χ	Н
h	X	1	L
h	Χ	h	Н

 $H = High \ logic \ level, h = High \ logic \ level$  one setup time prior to the low-to-high clock transition,  $L = Low \ logic \ level,$   $l = Low \ logic \ level$  one setup time prior to the low-to-high clock transition,  $L = Low \ logic \ level$  one setup time prior to the low-to-high clock transition,  $L = Low \ logic \ level$  one setup time prior to the low-to-high clock transition,

## logic diagram





## CY74FCT399T QUAD 2-INPUT REGISTER

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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential	0.5 V to 7 V
DC input voltage range	0.5 V to 7 V
DC output voltage range	0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 1)	57°C/W
Ambient temperature range with power applied, T <sub>A</sub>	-65°C to 135°C
Storage temperature range, T <sub>sta</sub>	-65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.75	5	5.25	V
VIH	High-level input voltage	2			V
V <sub>IL</sub>	Low-level input voltage			0.8	V
IOH	High-level output current			-32	mA
loL	Low-level output current			64	mA
TA	Operating free-air temperature	-40		85	°C

NOTE 2: All unused inputs of the device must be held at  $V_{\hbox{\footnotesize{CC}}}$  or GND to ensure proper device operation.



NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

## CY74FCT399T QUAD 2-INPUT REGISTER

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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT	
VIK	$V_{CC} = 4.75,$	$I_{IN} = -18 \text{ mA}$		-0.7	-1.2	V	
V	V 4.75	I <sub>OH</sub> = -32 mA	2			V	
VOH	V <sub>CC</sub> = 4.75	I <sub>OH</sub> = -15 mA		2.4	3.3		V
V <sub>OL</sub>	$V_{CC} = 4.75,$	I <sub>OL</sub> = 64 mA			0.3	0.55	V
VH	All inputs				0.2		V
lj	V <sub>CC</sub> = 5.25 V,	VIN = VCC				5	μΑ
lн	V <sub>CC</sub> = 5.25 V,	V <sub>IN</sub> = 2.7 V				±1	μΑ
Ι <sub>ΙL</sub>	V <sub>CC</sub> = 5.25 V,	V <sub>IN</sub> = 0.5 V				±1	μΑ
los <sup>‡</sup>	V <sub>CC</sub> = 5.25 V,	V <sub>OUT</sub> = 0 V	-60	-120	-225	mA	
l <sub>off</sub>	V <sub>CC</sub> = 0 V,	V <sub>OUT</sub> = 4.5 V				±1	μΑ
Icc	V <sub>CC</sub> = 5.25 V,	$V_{IN} \le 0.2 V$ ,	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2	mA
ΔlCC	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = 3	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = 3.4 V§, f <sub>1</sub> = 0, Outputs open				2	mA
lccd¶	$V_{CC} = 5.25 \text{ V}$ , One in $V_{IN} \le 0.2 \text{ V}$ or $V_{IN} \ge 0.2 \text{ V}$	put switching at 50% duty o	cycle, Outputs open,		0.06	0.12	mA/ MHz
	V <sub>CC</sub> = 5.25 V,	One input switching at f <sub>1</sub> = 5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4	
IC#	$f_0 = 10 \text{ MHz},$	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1.2	3.4	mA
ıC.,	Outputs open, S = Steady state	Four inputs switching at f <sub>1</sub> = 5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		1.6	3.2	MA
	at 50% du		V <sub>IN</sub> = 3.4 V or GND		2.9	8.2	
C <sub>i</sub>		-	•		5	10	pF
Co					9	12	pF

<sup>†</sup> Typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

# I<sub>C</sub> = I<sub>CC</sub> +  $\Delta$ I<sub>CC</sub> × D<sub>H</sub> × N<sub>T</sub> + I<sub>CCD</sub> (f<sub>0</sub>/2 + f<sub>1</sub> × N<sub>1</sub>) Where:

I<sub>C</sub> = Total supply current

ICC = Power-supply current with CMOS input levels

 $\Delta I_{CC}$  = Power-supply current for a TTL high input ( $V_{IN} = 3.4 \text{ V}$ )

D<sub>H</sub> = Duty cycle for TTL inputs high N<sub>T</sub> = Number of TTL inputs at D<sub>H</sub>

ICCD = Dynamic current caused by an input transition pair (HLH or LHL)

f<sub>0</sub> = Clock frequency for registered devices, otherwise zero

f<sub>1</sub> = Input signal frequency

N<sub>1</sub> = Number of inputs changing at f<sub>1</sub>

All currents are in milliamperes and all frequencies are in megahertz.

Values for these conditions are examples of the I<sub>CC</sub> formula.



Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, I<sub>OS</sub> tests should be performed last.

<sup>§</sup> Per TTL-driven input (V<sub>IN</sub> = 3.4 V); all other inputs at V<sub>CC</sub> or GND

<sup>¶</sup> This parameter is derived for use in total power-supply calculations.

## CY74FCT399T QUAD 2-INPUT REGISTER

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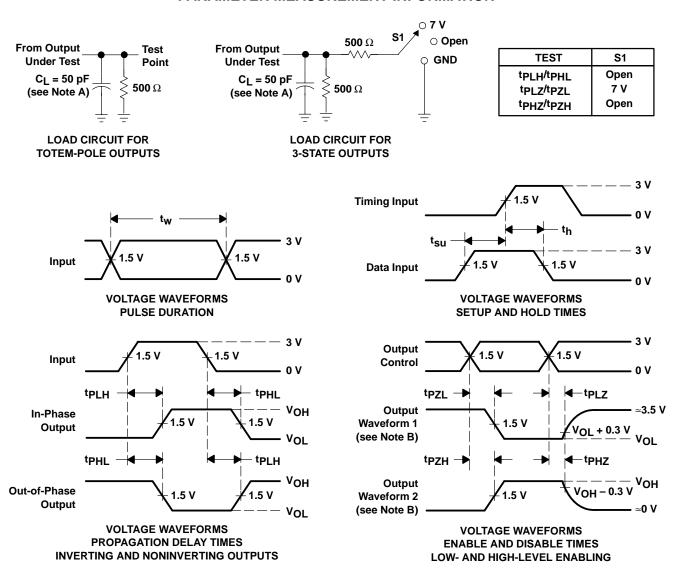
# timing requirement over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			CY74FC1	399AT	CY74FCT	399CT	UNIT
			MIN	MAX	MIN	MAX	UNII
t <sub>w</sub> Pulse duration, CP high or low					5		ns
	Cotup time high or low	I <sub>n</sub> before CP↑	3.5		3.5		
t <sub>su</sub>	Setup time, high or low	S before CP↑	8.5		8.5		ns
4.	I <sub>n</sub> after CP		1		1		
th	Hold time, high or low	S after CP↑	0		0		ns

## switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	CY74FC1	T399AT	CY74FC1	Г399СТ	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
t <sub>PLH</sub>	СР	0	2.5	7	2.5	6.1	no
<sup>t</sup> PHL	CP	ď	2.5	7	2.5	6.1	ns

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms







30-Aug-2005

#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CY74FCT399ATQCT	ACTIVE	SSOP/ QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT399ATQCTE4	ACTIVE	SSOP/ QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT399ATSOC	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT399ATSOCE4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT399ATSOCT	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT399ATSOCTE4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT399CTQCT	ACTIVE	SSOP/ QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT399CTQCTE4	ACTIVE	SSOP/ QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
CY74FCT399CTSOC	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT399CTSOCE4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT399CTSOCT	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT399CTSOCTE4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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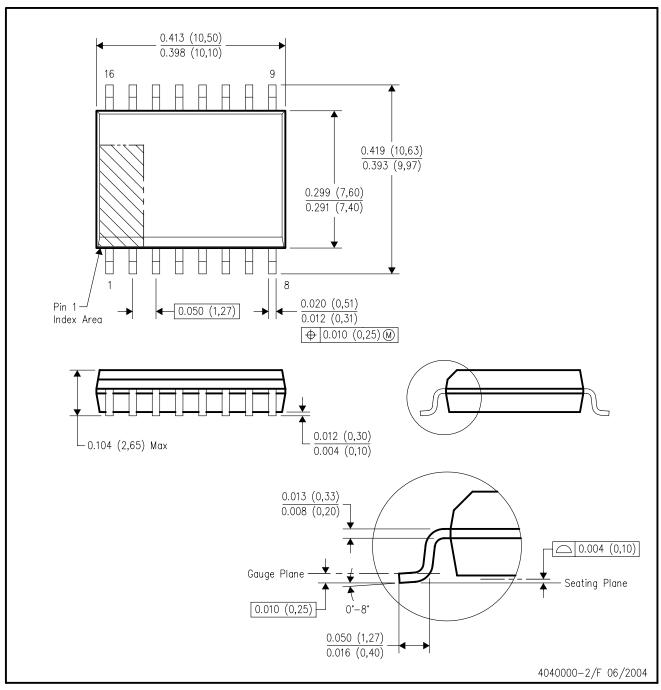
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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## DW (R-PDSO-G16)

## PLASTIC SMALL-OUTLINE PACKAGE



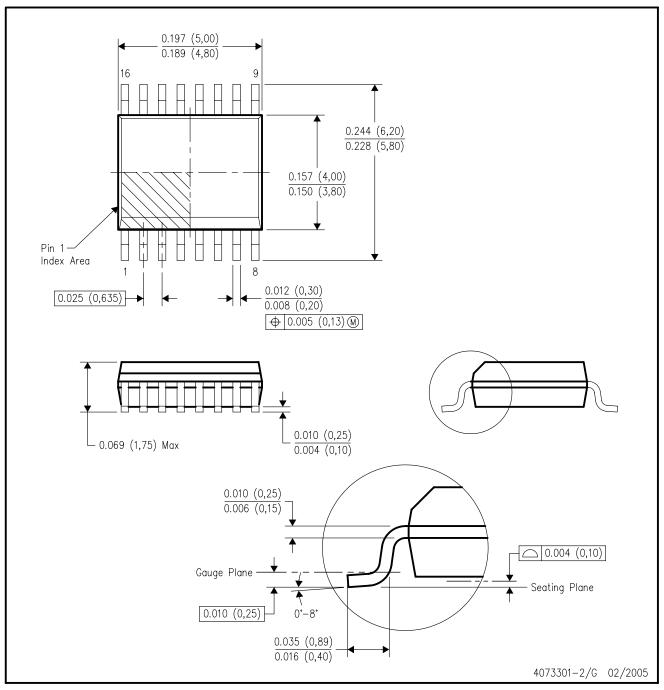
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AA.



# DBQ (R-PDSO-G16)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AB.



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